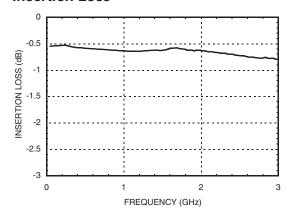


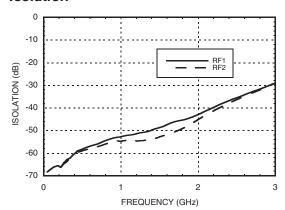


# GaAs MMIC SPDT SWITCH DC - 3 GHz

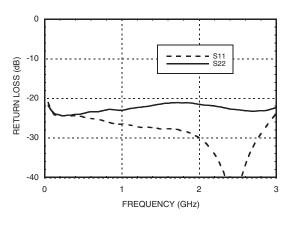
### **Insertion Loss**



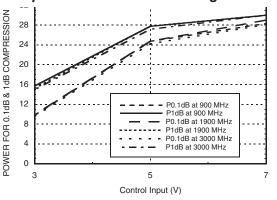
### Isolation



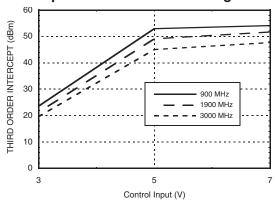
### **Return Loss**



Input 0.1 and 1.0 dB Compression vs. Control Voltage



# Input Third Order Intercept Point vs. Control Voltage



Truth Table

\*Control Input Voltage Tolerances are ± 0.2 Vdc.

| Control Input* |            | Control Current |            | Signal Path State |              |
|----------------|------------|-----------------|------------|-------------------|--------------|
| A<br>(Vdc)     | B<br>(Vdc) | la<br>(uA)      | lb<br>(uA) | RF to<br>RF1      | RF to<br>RF2 |
| 0              | +3         | -0.05           | +0.05      | ON                | OFF          |
| +3             | 0          | +0.05           | -0.05      | OFF               | ON           |
| 0              | +5         | -2              | +2         | ON                | OFF          |
| +5             | 0          | +2              | -2         | OFF               | ON           |
| 0              | +7         | -15             | +15        | ON                | OFF          |
| +7             | 0          | +15             | -15        | OFF               | ON           |

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# GaAs MMIC SPDT SWITCH DC - 3 GHz

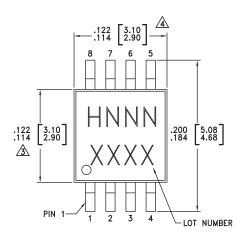
### **Absolute Maximum Ratings**

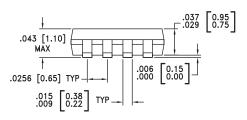
| RF Input Power (Vctl= 0V/+5V)                                 | +27 dBm          |  |
|---|------------------|--|
| Control Voltage Range (A & B)                                 | -0.2 to +7.5 Vdc |  |
| Hot Switch Power Level (Vctl= 0V/+5V)                         | +24 dBm          |  |
| Channel Temperature   | 150 °C           |  |
| Continuous Pdiss (T= 85 °C)<br>(derate 5.5 mW/°C above 85 °C) | 360 mW           |  |
| Thermal Resistance  | 180 °C/W         |  |
| Storage Temperature   | -65 to +150 °C   |  |
| Operating Temperature   | -40 to +85 °C    |  |
| ESD Sensitivity (HBM)   | Class 1B         |  |

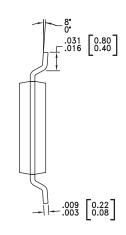
Note: DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.

# ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

### **Outline Drawing**







- 1. LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 🛕 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
- 6. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.

### Package Information

| Part Number | Package Body Material   | Lead Finish  | MSL Rating | Package Marking [3] |
|-------------|---|--------------|------------|---------------------|
| HMC194MS8   | Low Stress Injection Molded Plastic                           | Sn/Pb Solder | MSL1 [1]   | H194<br>XXXX        |
| HMC194MS8E  | HMC194MS8E RoHS-compliant Low Stress Injection Molded Plastic |              | MSL1 [2]   | H194<br>XXXX        |

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

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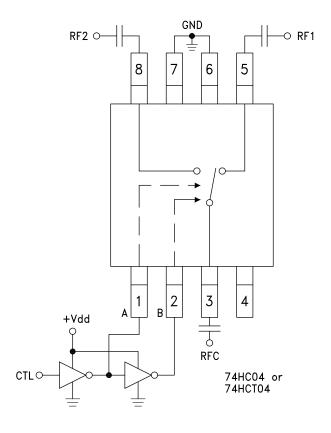
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com





# GaAs MMIC SPDT SWITCH DC - 3 GHz

### **Typical Application Circuit**



### Notes:

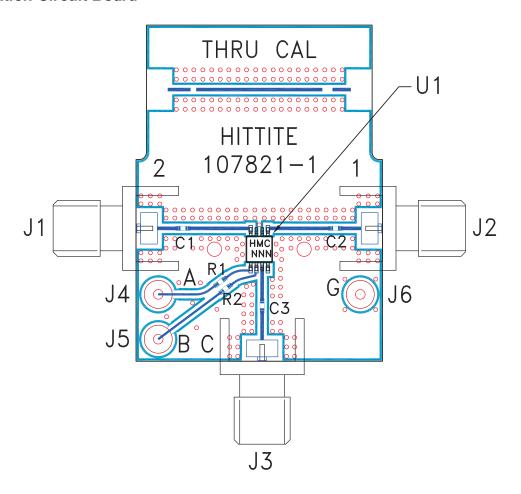
- 1. Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
- 2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of 3 to 7 Volts applied to the CMOS logic gates.
- 3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- 4. Highest RF signal power capability is achieved with Control set to 0/+7V.





# GaAs MMIC SPDT SWITCH DC - 3 GHz

### **Evaluation Circuit Board**



### List of Materials for Evaluation PCB 105143 [1]

| Item    | Description                           |
|---------|---------------------------------------|
| J1 - J3 | PC Mount SMA RF Connector             |
| J4 - J6 | DC Pin                                |
| C1 - C3 | 100 pF capacitor, 0402 Pkg.           |
| R1, R2  | 100 Ω resistor, 0402 Pkg.             |
| U1      | HMC194MS8 / HMC194MS8E<br>SPDT Switch |
| PCB [2] | 107821 Evaluation PCB                 |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.



# **HMC194MS8/ HMC194MS8**

v06.0608



**Notes** 

GaAs MMIC SPDT SWITCH DC - 3 GHz

SWITCHES - SMT